

What is Fault Injection?

Fault injection attacks intentionally cause errors in a system in order to compromise the security of the system

Non-invasive Fault Injection Attacks

■ Clock Glitching

- ❑ Burst of double clock speed – timing critical
- ❑ Requires knowledge gained from side-channel attack
- ❑ Prevent flip-flops from latching correct data
- ❑ Prevent security fuses from setting properly
- ❑ Could cause skipping instructions

■ Voltage Glitching

- ❑ Burst of high or low voltage – timing critical
- ❑ Requires knowledge gained from side-channel attack
- ❑ Force $VDD < V_{TH}$
- ❑ Prevent security fuses from setting properly
- ❑ Change control logic outputs
- ❑ Change memory amplifier outputs

Semi-invasive Fault Injection Attacks

■ Local Heating

- ❑ High power laser is used to selectively heat small areas
- ❑ Hot enough to change VTH but not hot enough to damage
- ❑ Trial and error with location is used to determine glitches

■ Flash Glitching

- ❑ Magnified camera flash can cause mass glitching
- ❑ Tinfoil masks created to cause selective glitching
- ❑ Trial and error with location and timing is used to determine glitches

■ Laser Glitching

- ❑ Infrared laser is used to selectively glitch small areas
 - ❑ Trial and error with location and timing is used to determine glitches
 - ❑ Process is more precise than Flash Glitching
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IC Modification

■ Laser Cutting

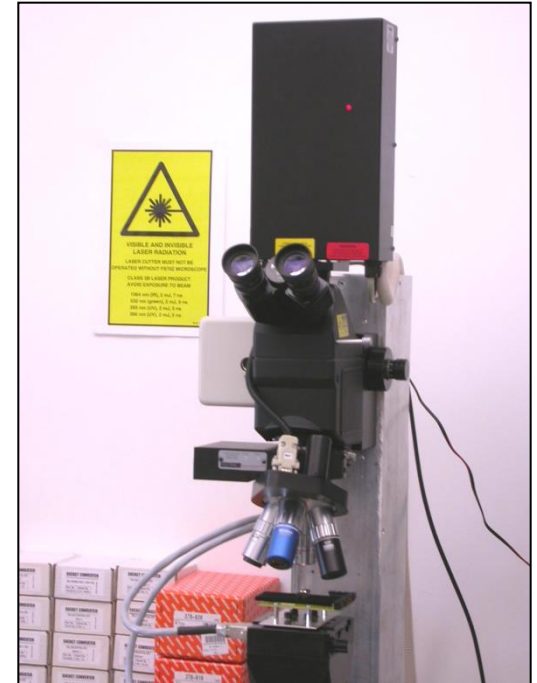
- ❑ Not completely destructive
- ❑ Selective exposure of lower layers
- ❑ Selectively disconnect nets

■ Test Point Creation

- ❑ Cut test points into IC
- ❑ More spots for micro probing below top layer
- ❑ See more signals on more nets

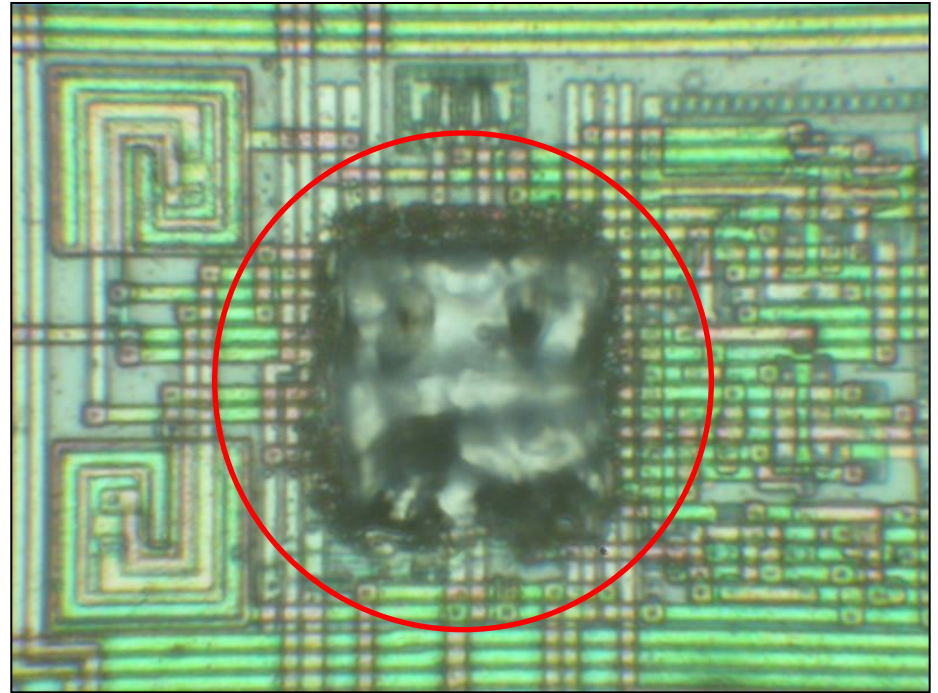
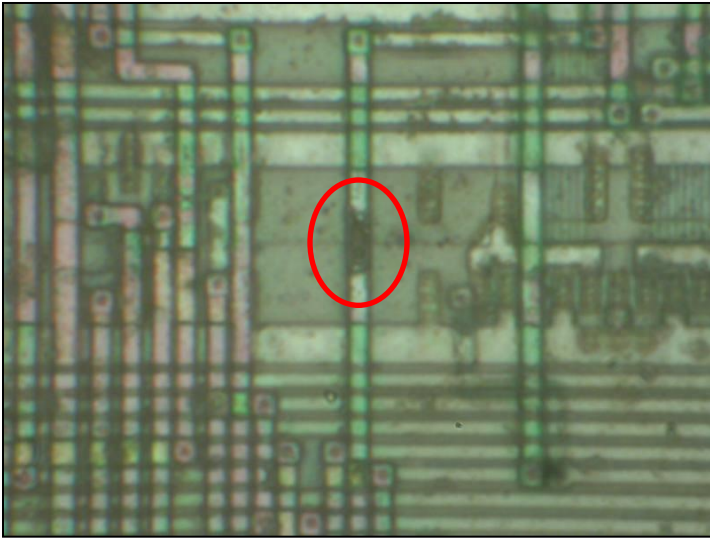
■ Wire Bonding

- ❑ Use laser cutting to expose net
- ❑ Cut test point for bonding target
- ❑ Modify circuit paths as needed



Source: Skorobogatov.
Semi-Invasive Attacks.
Page 85

Example of Laser Cutting



Source: Skorobogatov. Semi-Invasive Attacks. Page 88

Micro Probing

■ Eavesdropping

- ❑ Listen to control lines
- ❑ Listen to data bus
- ❑ Full bypass of all protections

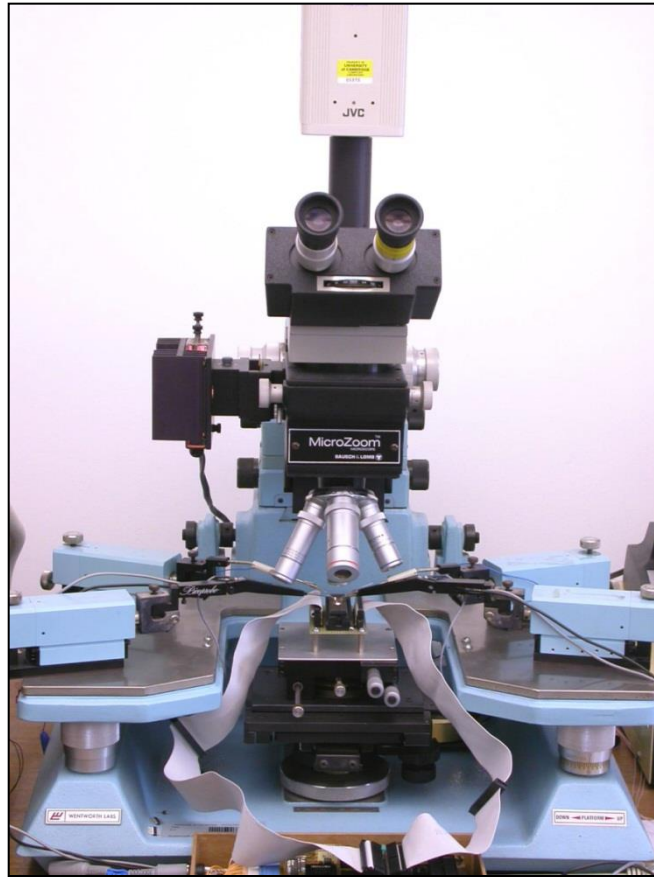
■ Signal Injection

- ❑ Insert control signals
- ❑ Modify memory contents
- ❑ Forcefully bypass security controls

■ Fault Injection

- ❑ High voltage between two probes
 - ❑ Destroy transistors
 - ❑ Destroy traces
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Sample Micro Probing Station



Source: Skorobogatov. Semi-Invasive Attacks. Page 84

Countermeasures

Clock Glitching

- **Internal oscillator for bootloader code**
- **Internal oscillator for secure functions**
- **Make security fuses faster than control logic**
- **Asynchronous logic**

Voltage Glitching

- **Internal brownout reset**
- **Different voltage threshold for security fuses**

IC Modification

- **Metal protection layers on top**
- **Critical signals routed on top of important targets**
- **Tamper sensors in metal layers**

Micro Probing

- **Tamper sensors in metal layers**
 - **Small transistor size**
 - **Internal shielding**
 - **Top level shielding**
 - **Security through obscurity**
 - **Glue Logic**
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Memory Attacks

- **UV Protection**
- **Temperature lockout sensors**
- **Tamper sensors to detect decapsulation**
- **Close proximity between security fuses and memory**

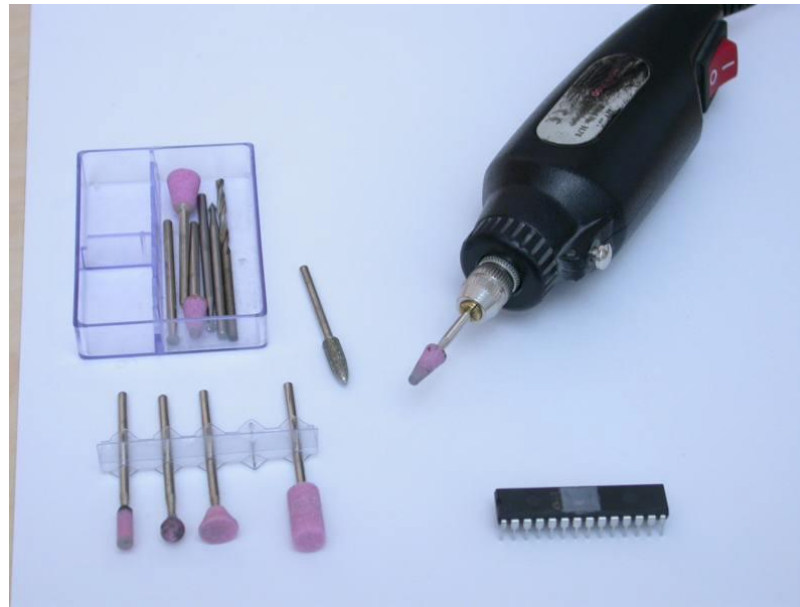
Optical Glitching

- **Protective metal layers to block optical penetration**
 - **Tamper sensors in metal layers**
 - **UV Protection**
 - **IR Protection**
 - **Proximity of security fuses and control logic to memory**
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Practical Fault Injection Attacks

Step 1: Backside Decapsulation

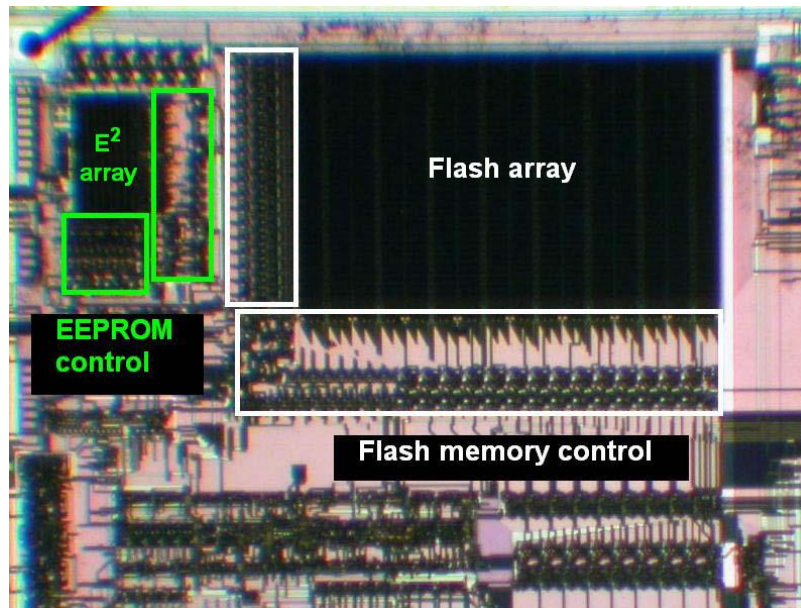
- Use dremel tool to remove backside of outer casing
- Clean surface of exposed substrate material
- Install the IC upside-down to a test interface board



Source: Skorobogatov. Semi-Invasive Attacks. Page 75

Step 2: Backside Imaging

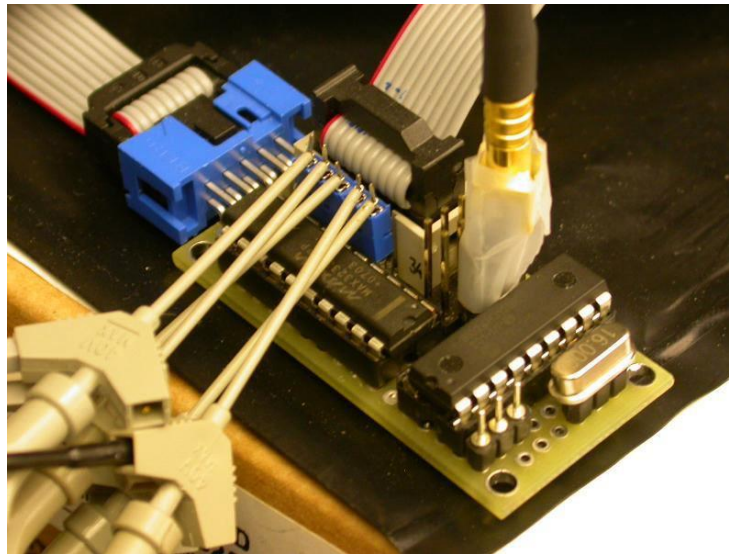
- Use 1000nm infrared light and an optical microscope
- Identify the location of the EEPROM/FLASH memory
- Identify the locations of the memory control logic
- Determine memory bus width



Source: Skorobogatov. Optical Fault Masking Attacks. Page 4

Step 3: Side Channel Attack

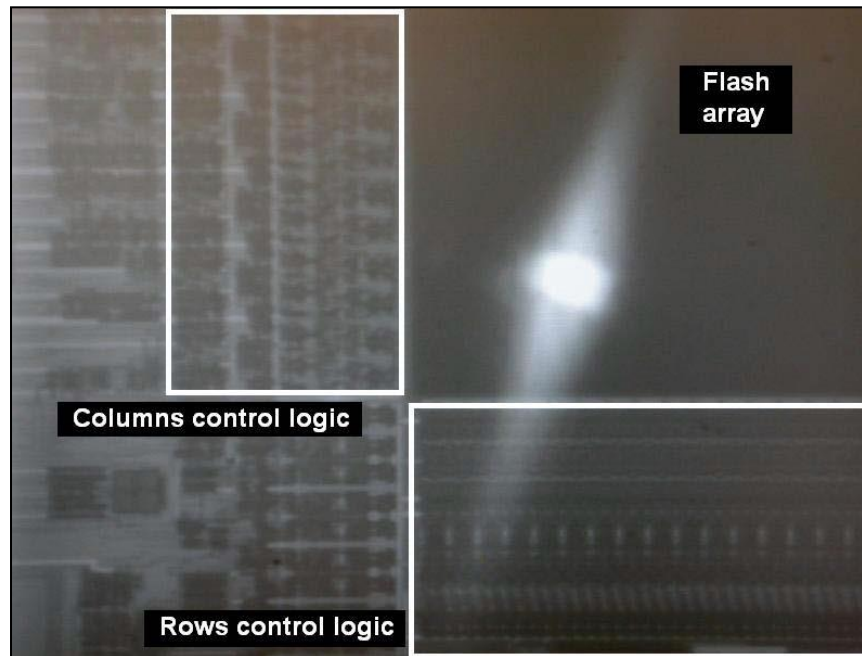
- Set up a power analysis attack using a 10ohm sense resistor
- Perform a Verify function on a dummy input
- Monitor transient current to reverse engineer the process
- Determine packet size of Verify function



Source: Skorobogatov. Flash Memory Bump Attacks. Page 7

Step 4: Laser Glitching Location

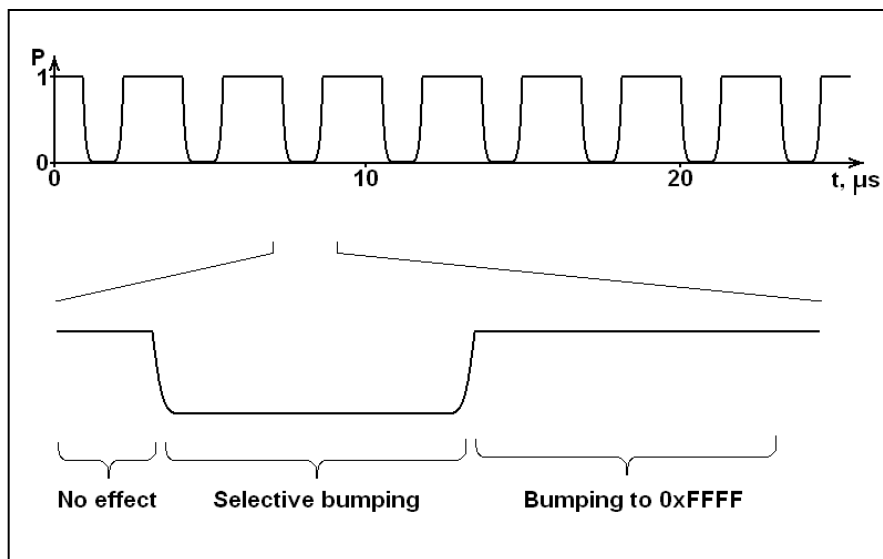
- Set Verify to a pattern of all '1' or all '0'
- Find a location in the memory control logic to attack
- Keep trying until your verify pattern succeeds



Source: Skorobogatov. Flash Memory Bump Attacks. Page 5

Step 5: Laser Glitching Timing

- Configure Laser timing to attack all but one block
- Verify that your timing delivers repeatable results
- Maximum unmasked length is the data bus width
- The fewer bits you can unmask at a time the better



Source: Skorobogatov. Flash Memory Bump Attacks. Page 12

Step 6: Brute Force Attack

- Perform a brute force attack on the first unmasked segment
 - Unmask the next segment and repeat
 - Repeat until all segments are determined
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- Example: Verification of a 1024 bit memory on an 8-bit bus
 - Traditional Brute Force = 2^{1024} Combinations
 - Bump Attack = $128 \cdot 2^8$ = 2^{15} Combinations
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- Example: Verification of a 16384 bit memory on a 16-bit bus
 - Traditional Brute Force = 2^{16384} Combinations
 - Bump Attack = $1024 \cdot 2^{16}$ = 2^{26} Combinations
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